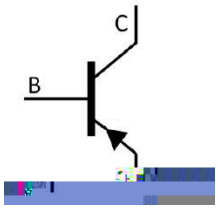
WR0<50 P ṂṂ Ł SQS ÆṀ ɥ s ǁ ˥ Silicon PNP transistor in a TO-92LM Plastic Package.

ɤ I_C ɤ V_{CBO}

High Collector current, high Collector-base voltage.

ȶ ˆ ˆ ˇ ı ' ω̈ ʑ

Power dissipation.



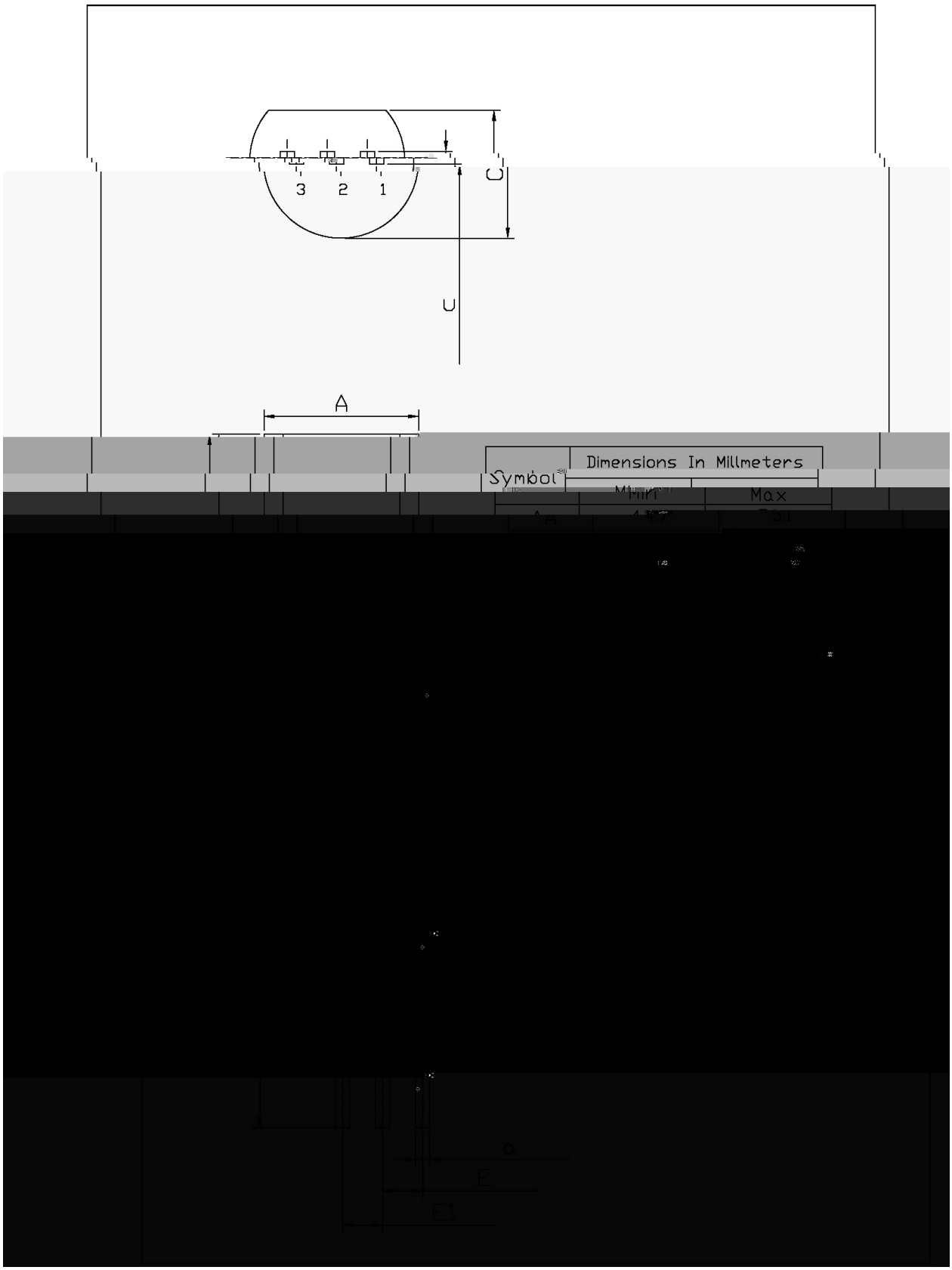


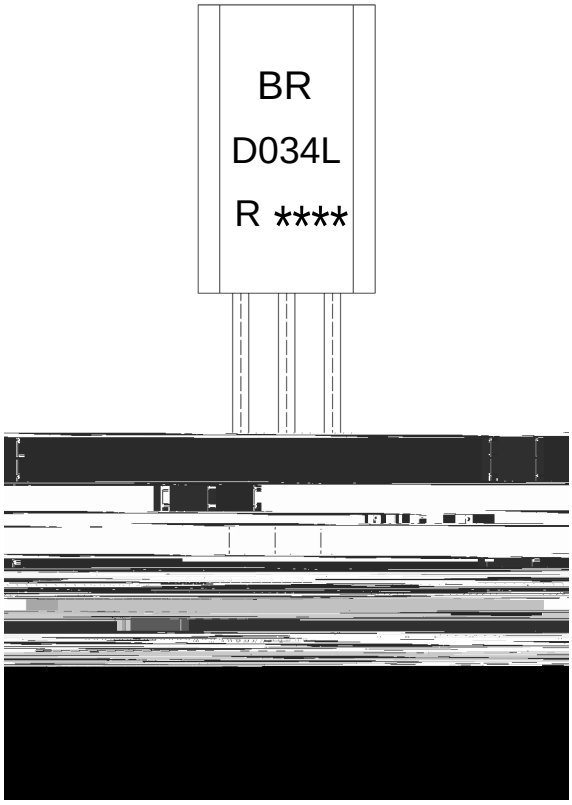
PIN1 χ Base PIN 2 χ Collector PIN 3 χ Emitter

h_{FE} Classifi05d8(c)3.7(a)2.5(d)00 [5625(tions 0]TJ-1.4057 -1.1486 TD-0.001 Tc0 Tw[(Symbol)-7.4( )]TJ13.6914 0.5714 TD-0.000

V ̈Ω Parameter	ϒ N Symbol	̈Ω Ö Rating	D Ӈ Unit
Collector to Base Voltage	V_{CBO}	-110	V
Collector to Emitter Voltage	V_{CEO}	-95	V
Emitter to Base Voltage	V_{EBO}	[illegible]	[illegible]

TO-92LM Unit: mm



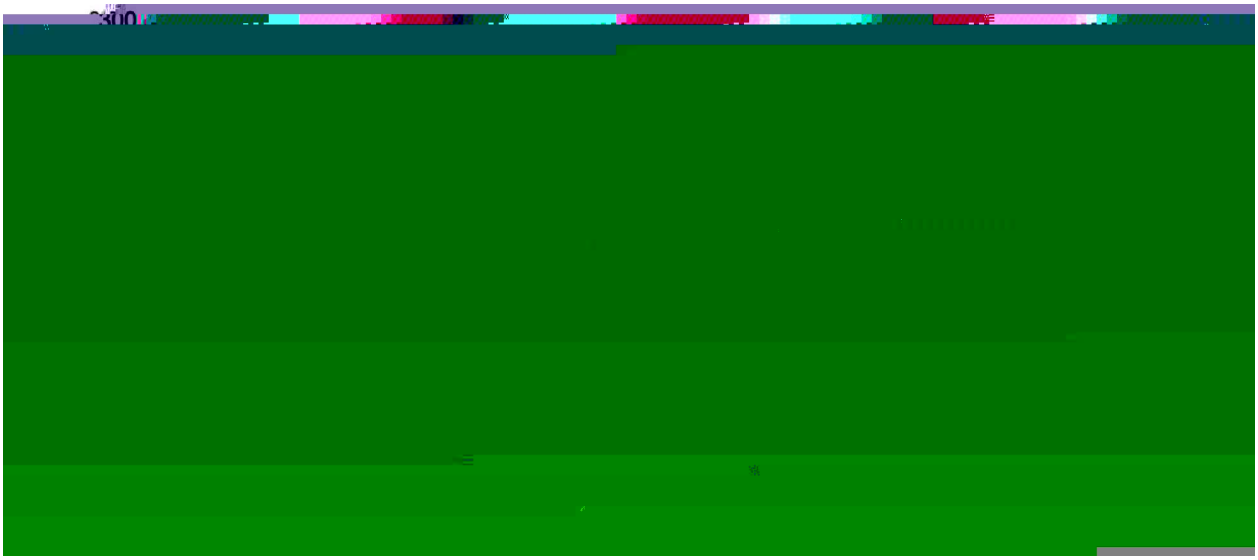


ب ˝ χ

EU=	ѭ ʒ ᴵᴵ Ɱ
G3670 χ	ѭ ʒ ᴺ Ɱ
U=	ѭ k_{IH} ʿ ᶠ Ɱ
---- χ	ѭ ɨ ɾ ŋ̈ ᴺ Ɱ ɪ ɞ ɨ ɾ ŋ̈ ᴺ ψ ק

Note:

BR:	Company Code.
D034L:	Product Type.
R:	h_{FE} Classifications Symbol
****:	Lot No. Code,code change with Lot No.



ب ˝ χ

1 ǂ ♬ □ ỷ 25 Ḱ 150 ɬ ı ̀H ڑ 60 Ḱ 90sec;

2 Š Ö □ ỷ 255 ° 5 ɬ ı ̀H ڑ ̀Y ⺈ ⺮ 5 ° 0.5sec;

3 ì ̇ ⺈ ˛ ɔ ھ ỷ ⺮ 2 Ḱ 10 ɬ /sec.

Note:

1.Preheating:25~150 ɬ , Time:60~90sec.

2.Peak Temp.:255 ° 5 ɬ , Duration:5 ° 0.5sec.

3. Cooling Speed: 2~10 ɬ /sec.

□ ỷ χ 270 ° 5 ɬ ̀H ڑ χ 10 ° 1 sec. Temp.:270±5 Time:10±1 sec

̈Ω ţ γ Ł / BULK

Package Type	Units			Dimension (unit mm3)
	Units/Bag /	Bags/Inner Box /	Units/Inner Box /	